

# Brückewell MS90N08 80V N-Channel MOSFET

## GENERAL DESCRIPTION

The MS90N08 is a N-channel enhancement-mode MOSFET, providing the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost effectiveness. The TO-220 package is universally preferred for all commercial-industrial applications

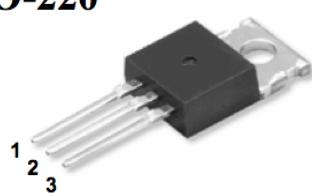
## FEATURES

- Low On Resistance
- Low Thermal Impedance
- Fast Switching Speed
- RoHS compliant / Halogen free package available

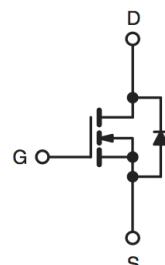
## APPLICATION

- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

**TO-220**



**1.Gate 2. Drain 3. Source**



PRODUCT SUMMARY		
VDS (V)	rDS(on) (mΩ)	ID(A)
80	11 @ VGS = 10V	90A
	13 @ VGS = 4.5V	

ABSOLUTE MAXIMUM RATINGS (TA = 25°C UNLESS OTHERWISE NOTED)			
Parameter	Symbol	Limit	Units
Drain-Source Voltage	VDS	80	V
Gate-Source Voltage	VGS	±20	
Continuous Drain Current a	ID	90a	A
Pulsed Drain Current b	IDM	350	
Continuous Source Current (Diode Conduction) a	IS	120	A
Power Dissipation a	PD	300	W
Operating Junction and Storage Temperature Range	TJ, Tstg	-55 to 175	°C

## THERMAL RESISTANCE RATINGS

Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient a	t <= 10 sec	62.5	°C/W
	Steady State		



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## Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static						
Gate-Source Threshold Voltage	VGS(th)	VDS = VGS, ID = 250 uA	1			V
Gate-Body Leakage	IGSS	VDS = 0 V, VGS = ±20 V			±100	nA
Zero Gate Voltage Drain Current	IDSS	VDS = 64 V, VGS = 0 V			1	uA
		VDS = 64V, VGS = 0 V, TJ = 55°C			25	
On-State Drain Current	ID(on)	VDS = 5 V, VGS = 10 V	45			A
Drain-Source On-Resistance	rDS(on)	VGS = 10 V, ID = 45 A			11	mΩ
		VGS = 4.5 V, ID = 44 A			13	
Forward Transconductance	gfs	VDS = 15 V, ID = 45 A		40		S
Diode Forward Voltage	VSD	IS = 60 A, VGS = 0 V		0.9		V
Dynamic						
Total Gate Charge	Qg	VDS = 40 V, VGS = 4.5 V, ID = 20 A		58		nC
Gate-Source Charge	Qgs			14		
Gate-Drain Charge	Qgd			39		
Turn-On Delay Time	td(on)	VDS = 40 V, RL = 2Ω, ID = 20 A, VGEN = 10 V, RGEN = 6 Ω		19		ns
Rise Time	tr			45		
Turn-Off Delay Time	td(off)			178		
Fall Time	tf			62		
Input Capacitance	Ciss	VDS = 15 V, VGS = 0 V, f = 1 MHz		4021		Pf
Output Capacitance	Coss			449		
Reverse Transfer Capacitance	Crss			440		

## Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

- Characteristic Curves

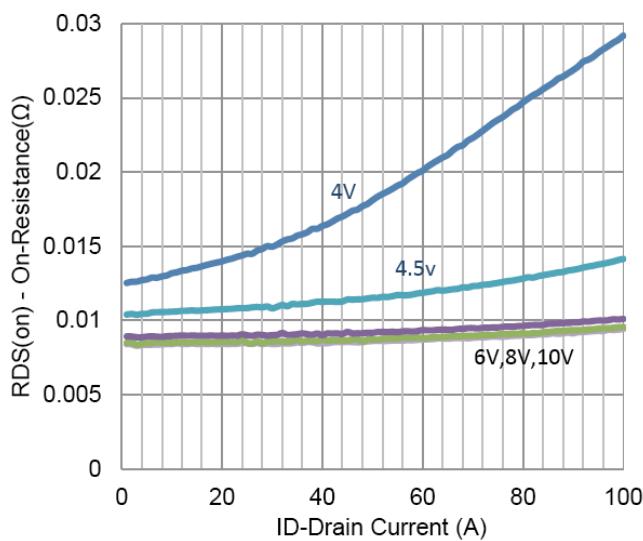


Figure 1. On Region Characteristics

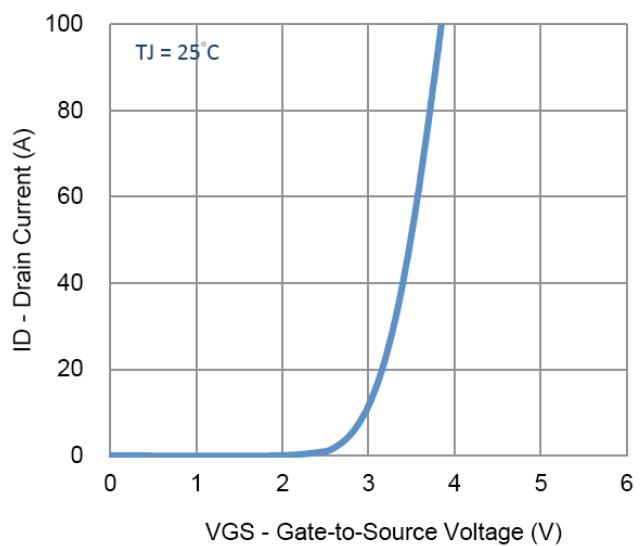


Figure 2. Transfer Characteristics

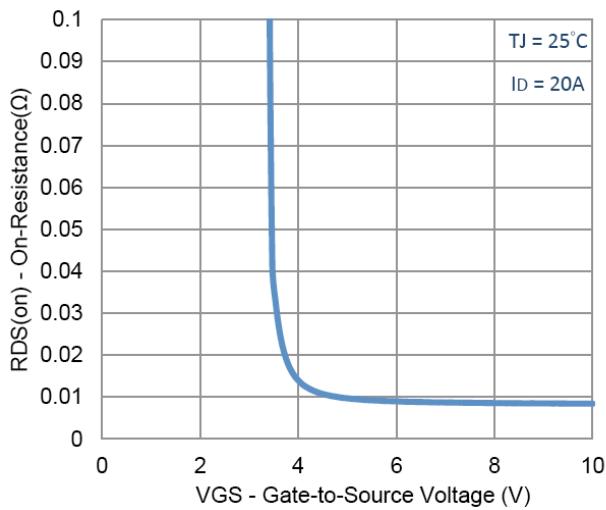


Figure 3. On Resistance Variation vs Drain Current and Gate Voltage

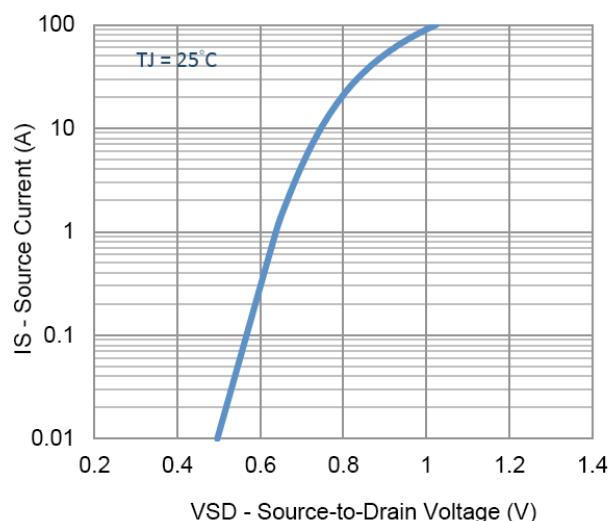


Figure 4. Body Diode Forward Voltage Variation with Source Current and Temperature

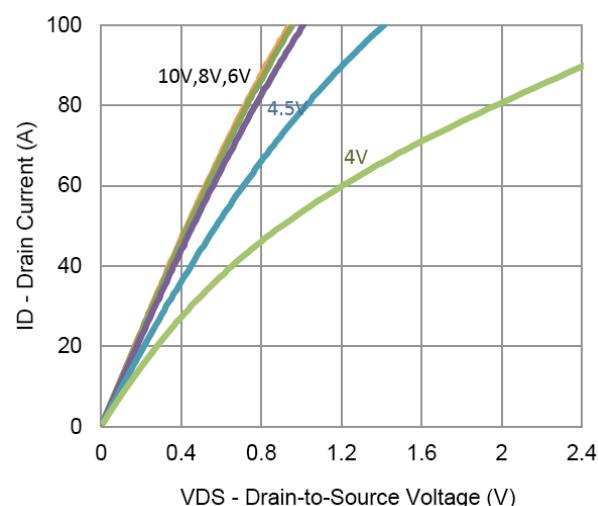


Figure 5. Output Characteristics

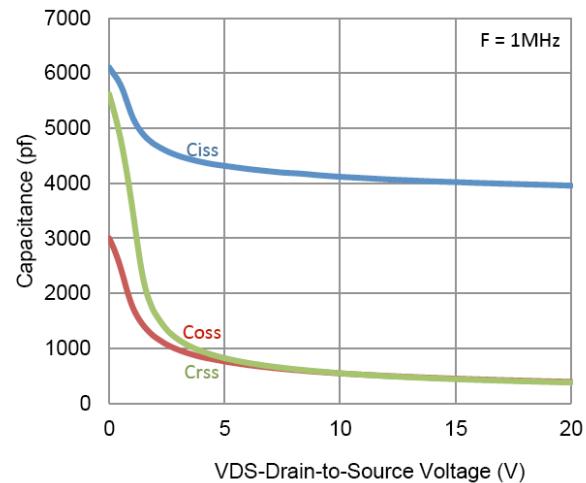
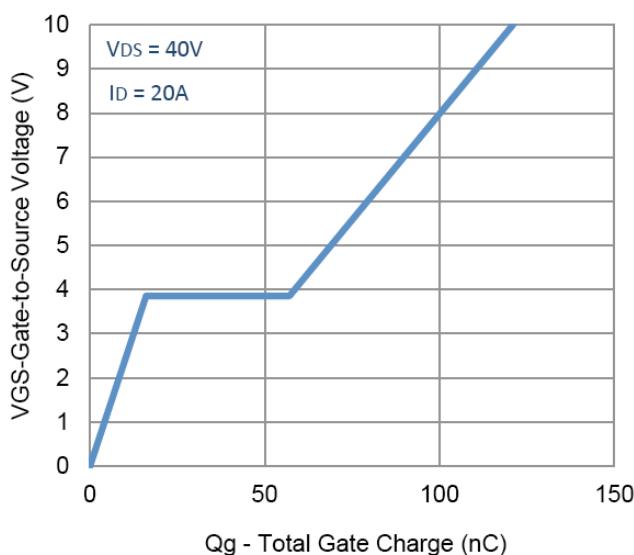


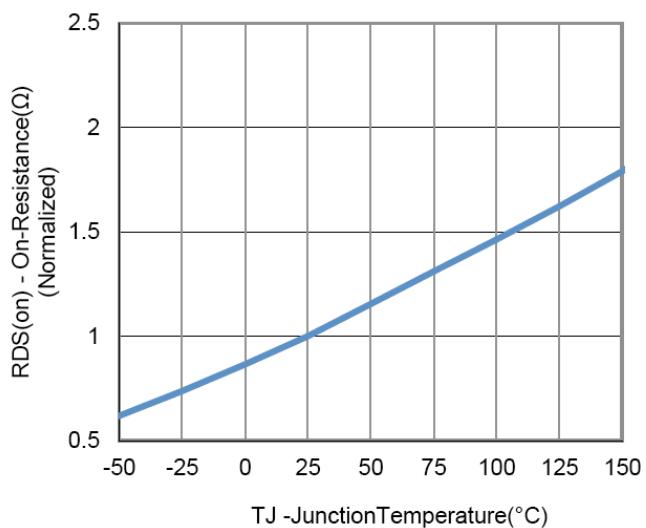
Figure 6. Capacitance Characteristics

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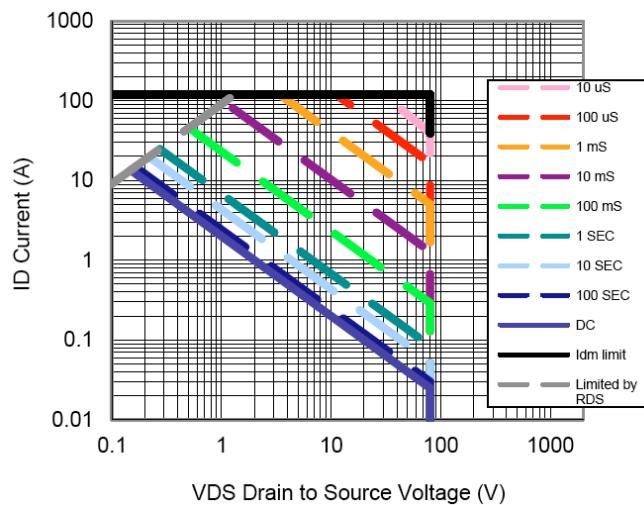
- Characteristic Curves



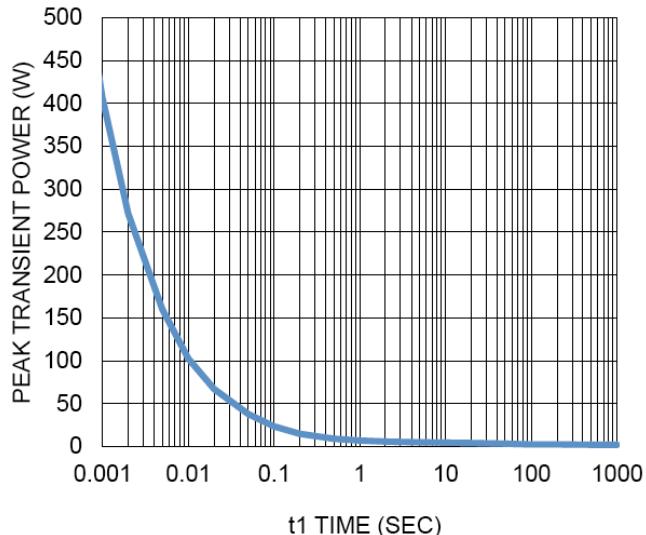
**Figure 7. Gate Charge**



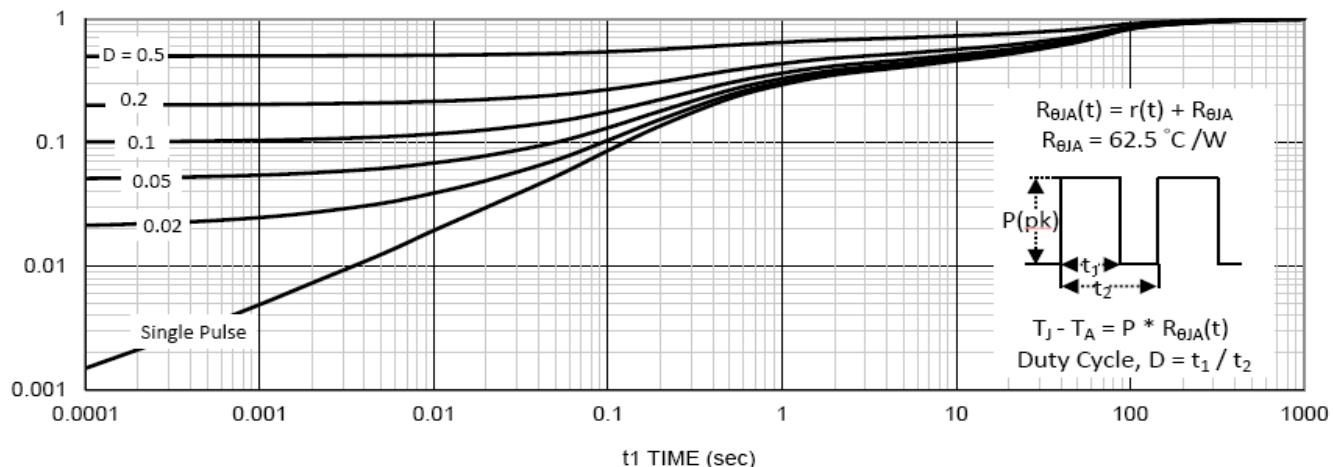
**Figure 8. Normalized On-Resistance Vs Junction Temperature**



**Figure 9. Maximum Safe Operating Area**



**Figure 10. Single Pulse Maximum Power Dissipation**



**Figure 11. Transient Thermal Response Curve**

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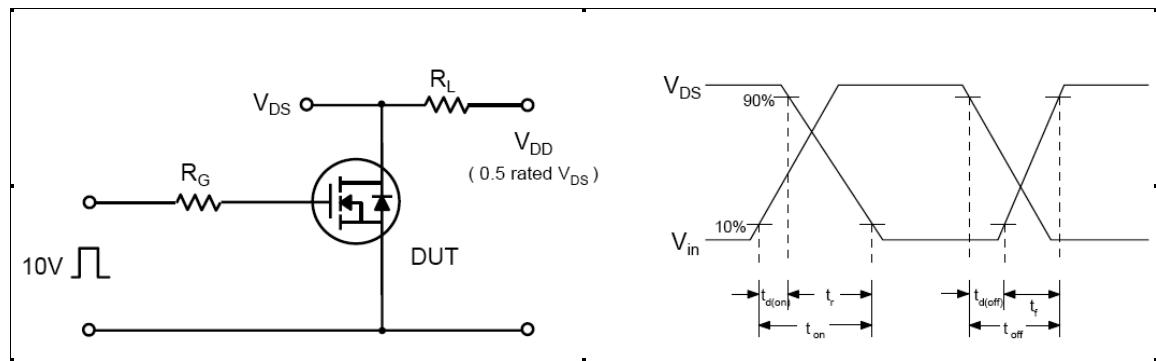


Fig 12. Resistive Switching Test Circuit & Waveforms

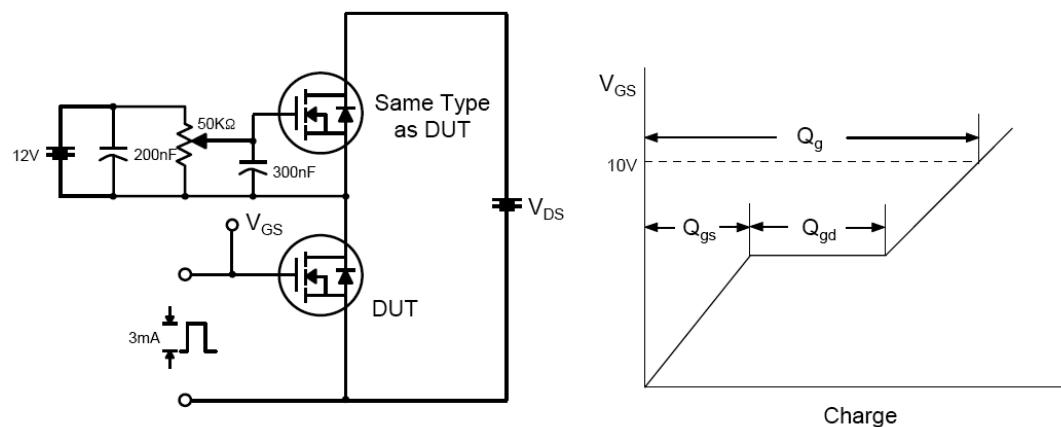


Fig 13. Gate Charge Test Circuit & Waveform

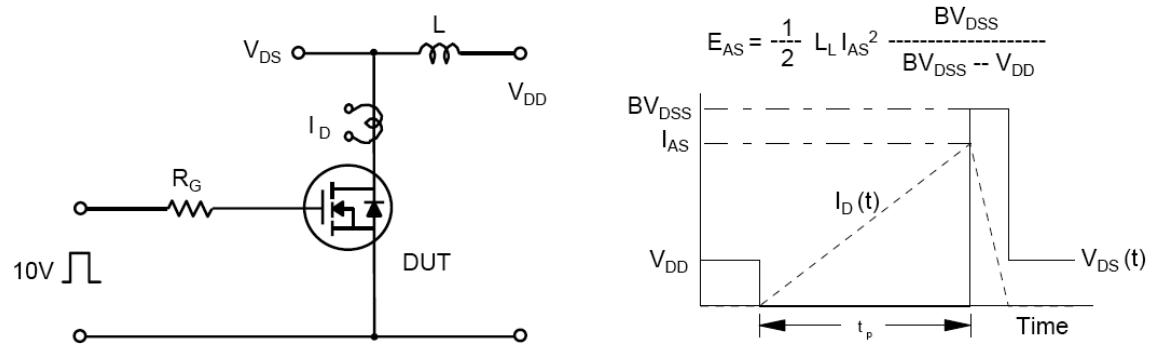


Fig 14. Unclamped Inductive Switching Test Circuit & Waveforms

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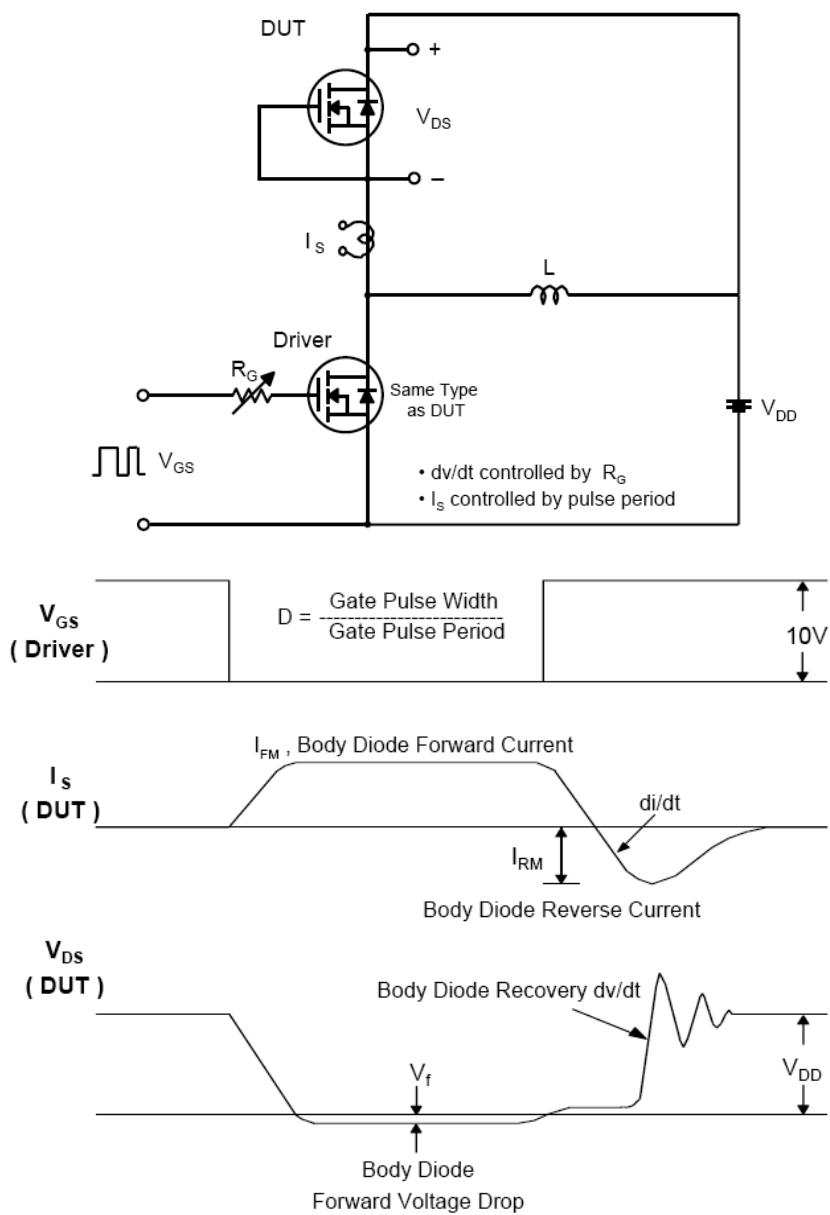
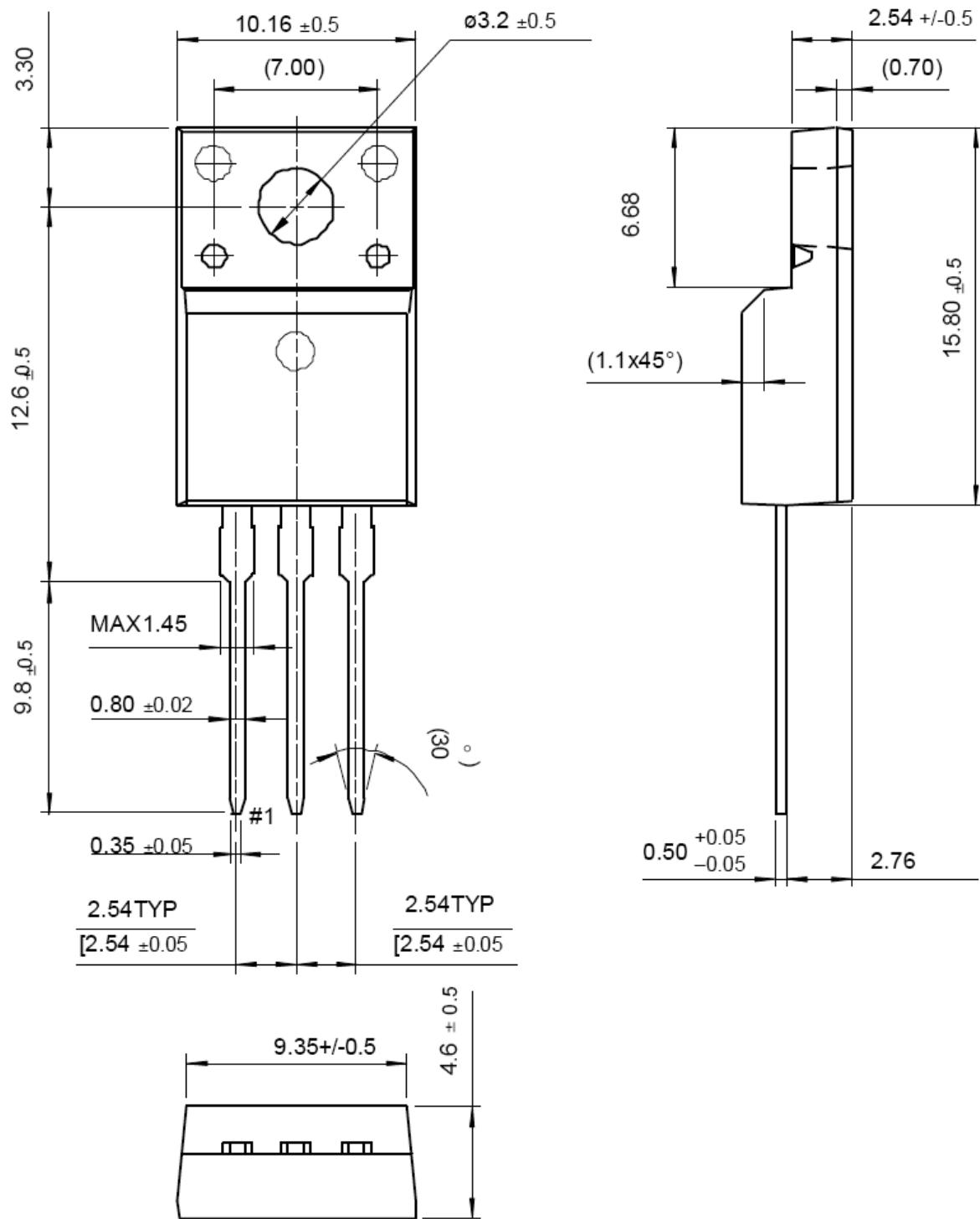


Fig 15. Peak Diode Recovery  $dv/dt$  Test Circuit & Waveforms

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## Package Dimensions

Dimensions in Millimeters





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## Legal Disclaimer Notice

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